NCP348, NCP348AE

Positive Overvoltage Protection Controller with Internal Low R_{ON} NMOS FET and Status FLAG

The NCP348 is able to disconnect the systems from its output pin in case wrong input operating conditions are detected. The system is positive overvoltage protected up to +28 V.

Due to this device using internal NMOS, no external device is necessary, reducing the system cost and the PCB area of the application board.

The NCP348 is able to instantaneously disconnect the output from the input, due to integrated Low R_{ON} Power NMOS (65 mΩ), if the input voltage exceeds the overvoltage threshold (OVLO) or undervoltage threshold (UVLO).

At powerup ($\overline{EN}$ pin = low level), the V_{out} turns on 50 ms after the V_{in} exceeds the undervoltage threshold.

The NCP348 provides a negative going flag ($\overline{FLAG}$) output, which alerts the system that a fault has occurred.

In addition, the device has ESD−protected input (15 kV Air) when bypassed with a 1.0 μF or larger capacitor.

Features

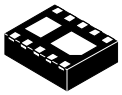
- Overvoltage Protection up to 28 V
- On−Chip Low $R_{DS(on)}$ NMOS Transistor: 65 mΩ
- Internal Charge Pump
- Overvoltage Lockout (OVLO)
- Undervoltage Lockout (UVLO)
- Internal 50 ms Startup Delay
- Alert $\overline{FLAG}$ Output
- Shutdown $\overline{EN}$ Input
- Compliance to IEC61000−4−2 (Level 4)
  - 8.0 kV (Contact)
  - 15 kV (Air)
- ESD Ratings: Machine Model = B
  Human Body Model = 3
- 10 Lead WDFN 2.5x2 mm Package
- This is a Pb−Free Device

Applications

- Cell Phones
- Camera Phones
- Digital Still Cameras
- Personal Digital Applications
- MP3 Players

ON Semiconductor®

http://onsemi.com



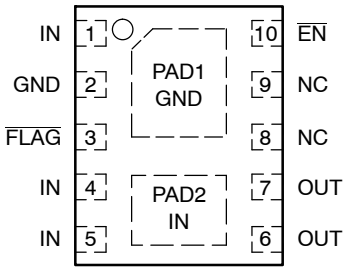
WDFN10
MT SUFFIX
CASE 516AA

MARKING DIAGRAM



BAI = NCP348
BAJ = NCP348AE
M = Date Code
▪ = Pb−Free Package

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

© Semiconductor Components Industries, LLC, 2010

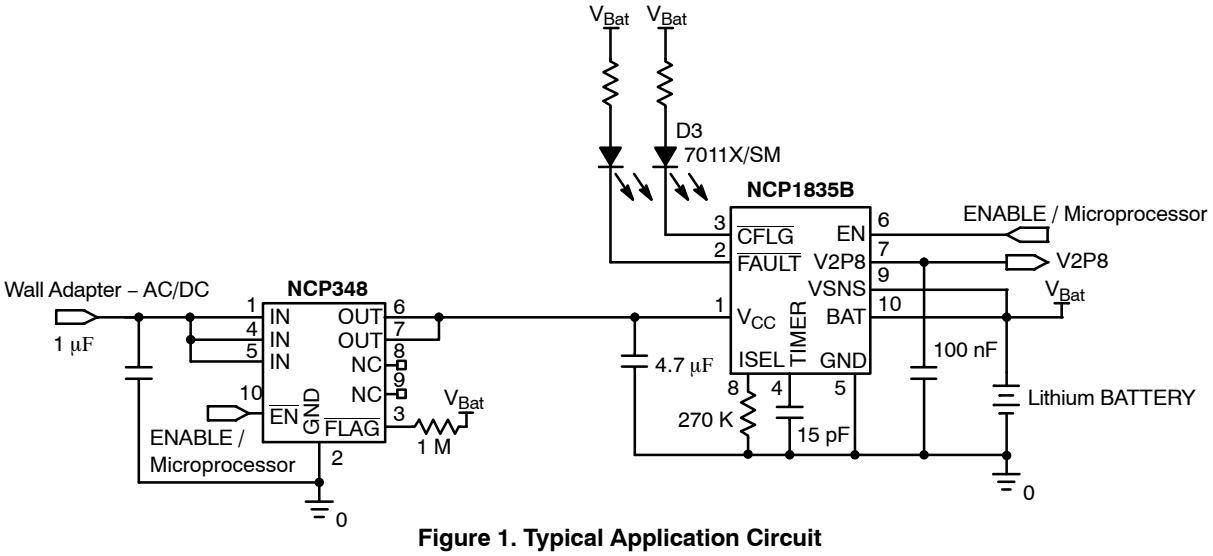


Figure 1. Typical Application Circuit

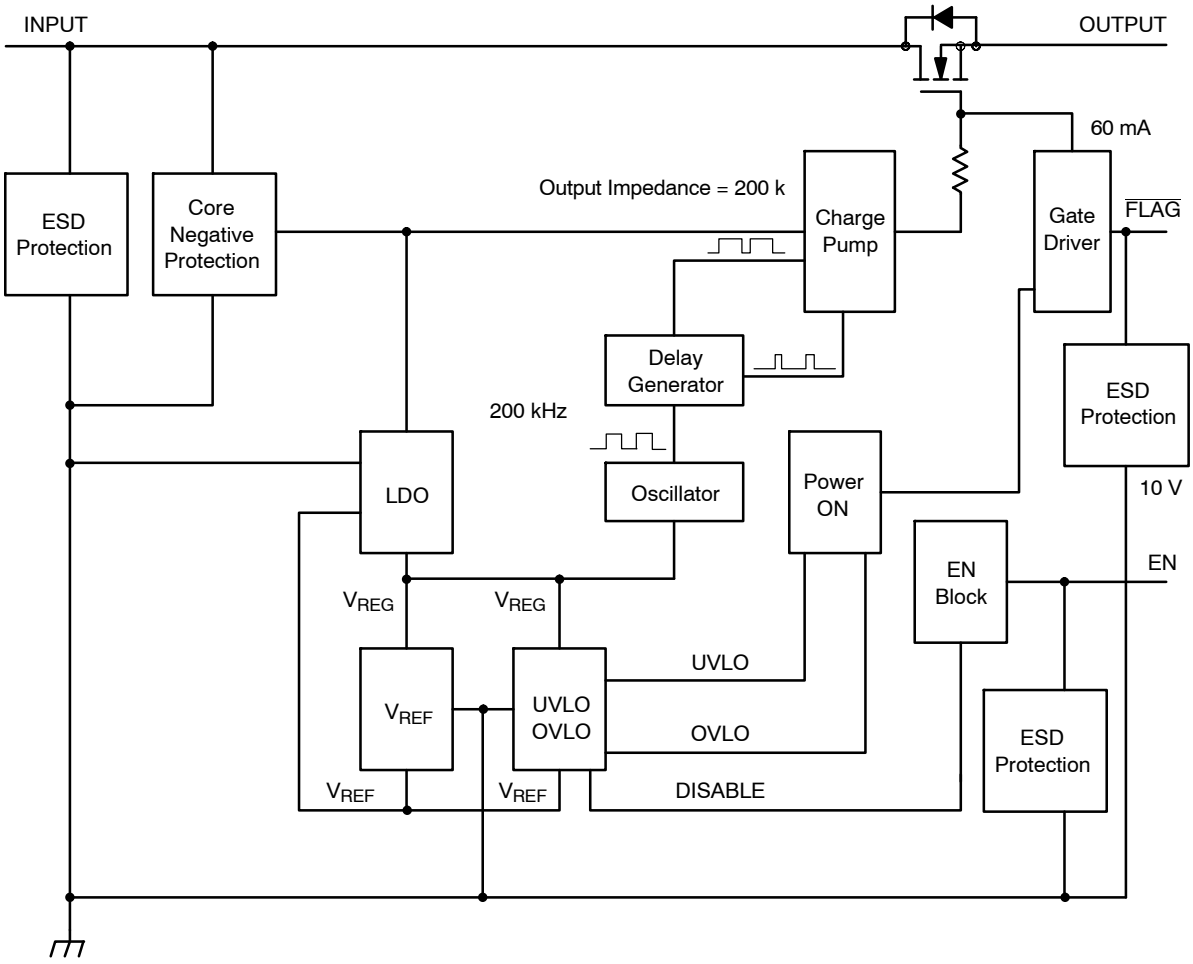


Figure 2. Functional Block Diagram

PIN FUNCTION DESCRIPTION

Pin No.	Symbol	Function	Description
1 4 5	IN	POWER	Input Voltage Pin. This pin is connected to the power supply. The device system core is supplied by this input. A 1 μF low ESR ceramic capacitor, or larger, must be connected between this pin and GND. The three IN pins must be hardwired to common supply.
2	GND	POWER	Ground
3	$\overline{\text{FLAG}}$	OUTPUT	Fault Indication Pin. This pin allows an external system to detect a fault on IN pin. The $\overline{\text{FLAG}}$ pin goes low when input voltage exceeds OVLO threshold or drop below UVLO threshold. Since the $\overline{\text{FLAG}}$ pin is open drain functionality, an external pull up resistor to V_{CC} must be added.
6 7	OUT	OUTPUT	Output Voltage Pin. This pin follows IN pin when “no fault” is detected. The output is disconnected from the V_{in} power supply when the input voltage is under the UVLO threshold or above OVLO threshold. The two OUT pins must be hardwired to common supply.
8	NC	OPEN	No Connect
9	NC	OPEN	No Connect
10	$\overline{\text{EN}}$	INPUT	Enable Pin. The device enters in shutdown mode when this pin is tied to a high level. In this case the output is disconnected from the input. To allow normal functionality, the $\overline{\text{EN}}$ pin shall be connected to GND to a pull down or to a I/O pin. This pin does not have an impact on the fault detection.
PAD1			PAD1, under the device. See PCB recommendations page 10. Can be shorted to GND.
PAD2			The PAD2 is electrically connected to the internal NMOS drain and connected to Pins 4 and 5. See PCB recommendations page 10.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Minimum Voltage (IN to GND)	$Vmin_{in}$	−0.3	V
Minimum Voltage (All others to GND)	Vmin	−0.3	V
Maximum Voltage (IN to GND)	$Vmax_{in}$	30	V
Maximum Voltage (All others to GND)	Vmax	7.0	V
Maximum Current (UVLO<V_{IN}<OVLO)	Imax	2.0	A
Thermal Resistance, Junction−to−Air (Note 1)	$R_{\theta JA}$	280	°C/W
Operating Ambient Temperature Range	T_A	−40 to +85	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Junction Operating Temperature	T_J	150	°C
ESD Withstand Voltage (IEC 61000−4−2) (input only) when bypassed with 1.0 μF capacitor Human Body Model (HBM), Model = 2 (Note 2) Machine Model (MM) Model = B (Note 3)	Vesd	15 Air, 8.0 Contact 2000 200	kV V V
Moisture Sensitivity	MSL	Level 1	−

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The $R_{\theta JA}$ is highly dependent on the PCB heat sink area (connected to pad 2). As example $R_{\theta JA}$ is 268 °C/W with 30 mm^2 (copper 35 μm) and 189 °C/W with 400 mm^2.
2. Human Body Model, 100 pF discharged through a 1.5 kΩ resistor following specification JESD22/A114.
3. Machine Model, 200 pF discharged through all pins following specification JESD22/A115.

ELECTRICAL CHARACTERISTICS (Min/Max limits values (−40°C < T_A < +85°C) and V_{in} = +5.0 V. Typical values are T_A = +25°C, unless otherwise noted.)

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{in}	–	1.2	–	28	V
Undervoltage Lockout Threshold (Note 4)	UVLO	–	3.0	3.25	3.5	V
Undervoltage Lockout Hysteresis	$UVLO_{hyst}$	–	20	50	100	mV
Overvoltage Lockout Threshold (Note 4) NCP348MTT NCP348AEMTT	OVLO	V_{in} rises up OVLO threshold	 6.0 5.7	 6.4 6.02	 6.8 6.4	V
Overvoltage Lockout Hysteresis NCP348MTT NCP348AEMTT	$OVLO_{hyst}$	–	 50 30	 100 60	 150 90	mV
V_{in} versus V_{out} Resistance	$R_{DS(on)}$	V_{in} = 5.0 V, $\overline{EN}$ = GND, Load connected to V_{out}	–	65	120	mΩ
Supply Quiescent Current	Idd	No load. $\overline{EN}$ = 5.0 V	–	90	150	μA
		No load. $\overline{EN}$ = Gnd	–	170	250	μA
UVLO Supply Current	Idd_{uvlo}	V_{IN} = 2.9 V	–	70	100	μA
$\overline{FLAG}$ Output Low Voltage	Vol_{flag}	1.2 V < V_{IN} < UVLO Sink 50 μA on/$\overline{FLAG}$ pin	–	20	400	mV
		V_{IN} > OVLO Sink 1.0 mA on $\overline{FLAG}$ pin	–	–	400	mV
$\overline{FLAG}$ Leakage Current	$\overline{FLAG}_{leak}$	$\overline{FLAG}$ level = 5.0 V	–	1.0	–	nA
$\overline{EN}$ Voltage High	Vih	–	1.2	–	–	V
$\overline{EN}$ Voltage Low	Vol	–	–	–	0.4	V
$\overline{EN}$ Leakage Current	$\overline{EN}_{leak}$	$\overline{EN}$ = 5.0 V or GND	–	1.0	–	nA
TIMINGS						
Startup Delay	ton	From V_{in}: (0 to (OVLO − 300 mV) < V_{in} < OVLO) to V_{out} = 0.3 V Rise time<4μs (See Figures 3 & 7)	30	55	70	ms
$\overline{FLAG}$ Going Up Delay	tstart	From V_{out} = 0.3 V to FLAG = 1.2 V (See Figures 3 & 9)	30	50	70	ms
Output Turn Off Time	toff	From V_{in} > OVLO to V_{out} < = 0.3 V (See Figures 4 & 8) V_{in} increasing from 5.0 V to 8.0 V at 3.0 V/μs, Rload connected on V_{out}	–	1.5	5.0	μs
Alert Delay	tstop	From V_{in} > OVLO to $\overline{FLAG}$ < = 0.4 V (See Figures 4 & 10) V_{in} increasing from 5.0 V to 8.0 V at 3.0 V/μs, Rload connected on V_{out}	–	1.0	–	μs
Disable Time	tdis	From $\overline{EN}$ > = 1.2 V to V_{out} < 0.3 V Rload = 5.0 Ω (See Figures 5 & 12)	–	1.0	5.0	μs

NOTE: Electrical parameters are guaranteed by correlation across the full range of temperature.

4. Additional UVLO and OVLO thresholds ranging from UVLO and from OVLO can be manufactured. Contact your ON Semiconductor representative for availability.

TIMING DIAGRAMS

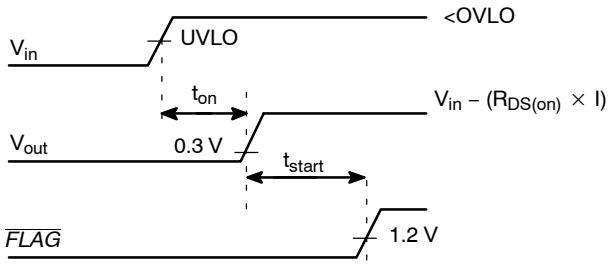


Figure 3. Startup

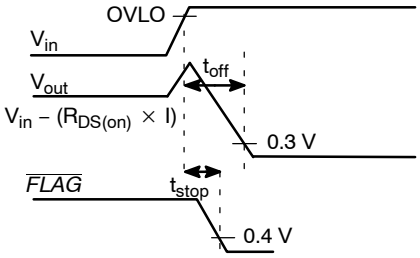


Figure 4. Shutdown on Overvoltage Detection

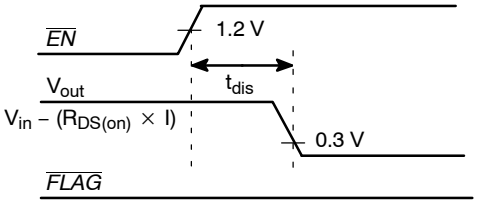


Figure 5. Disable on $\overline{EN}$ = 1

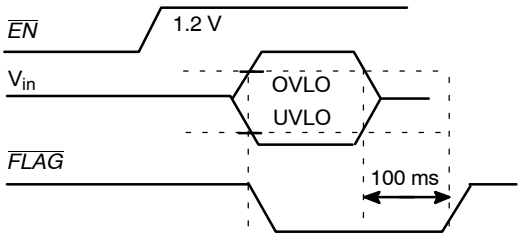


Figure 6. $\overline{FLAG}$ Response with $\overline{EN}$ = 1

TYPICAL OPERATING CHARACTERISTICS

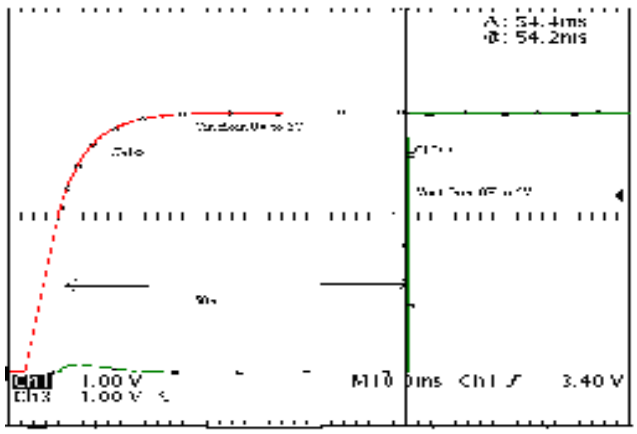


Figure 7. Startup
V_{in} = Ch1, V_{out} = Ch3

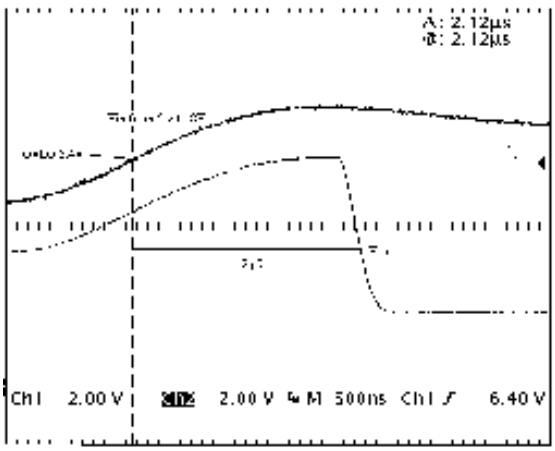


Figure 8. Output Turn Off Time
V_{in} = Ch1, V_{out} = Ch2

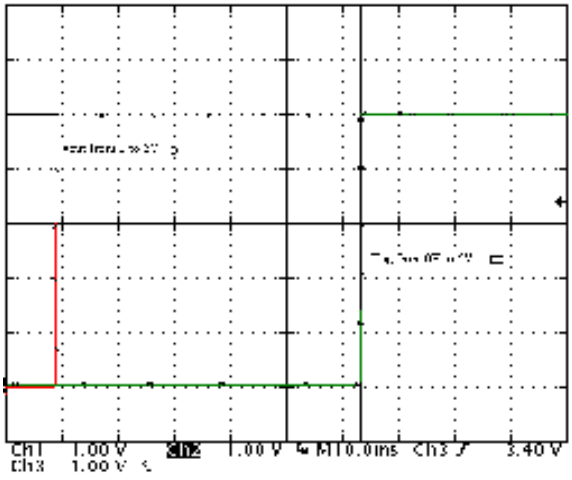


Figure 9. FLAG Going Up Delay
V_{out} = Ch3, FLAG = Ch2

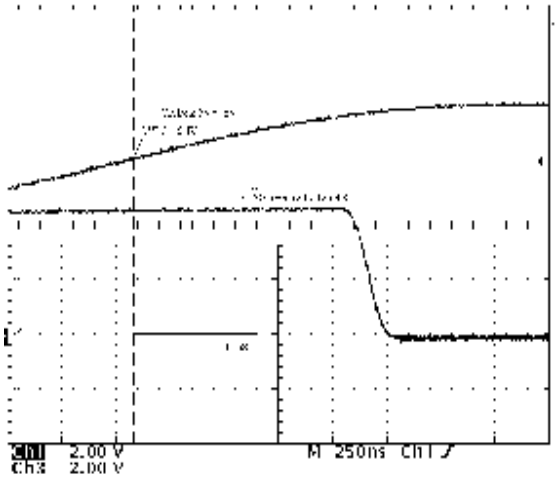


Figure 10. Alert Delay
V_{out} = Ch1, FLAG = Ch3

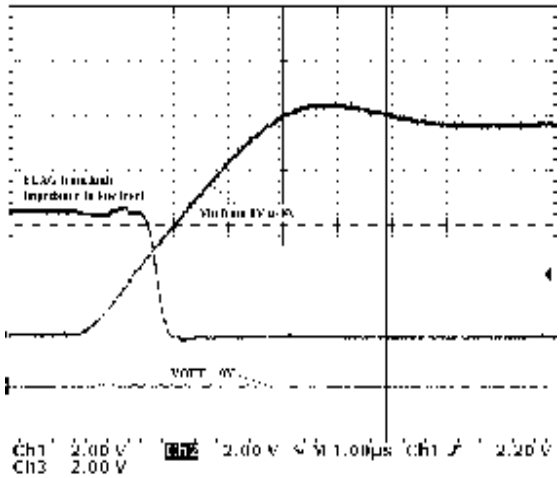


Figure 11. Initial Overvoltage Delay
V_{in} = Ch1, V_{out} = Ch2, FLAG = Ch3

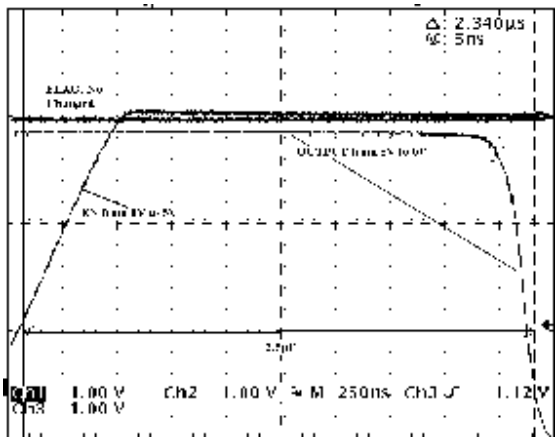


Figure 12. Disable Time
EN = Ch1, V_{out} = Ch2, FLAG = Ch3

TYPICAL OPERATING CHARACTERISTICS

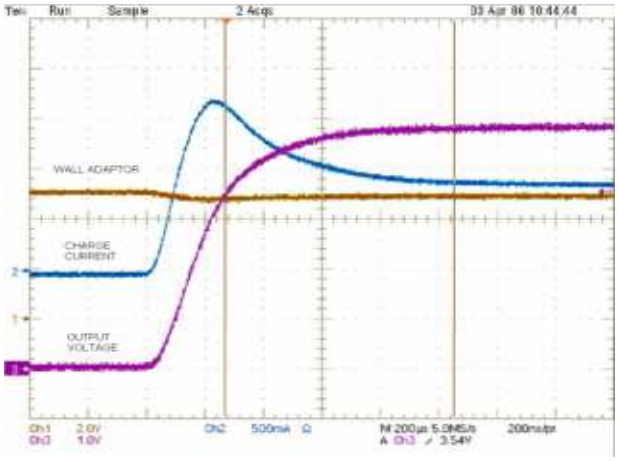


Figure 13. Inrush Current with C_{out} = 100 μF, I charge = 1 A, Output Wall Adaptor Inductance 1 μH

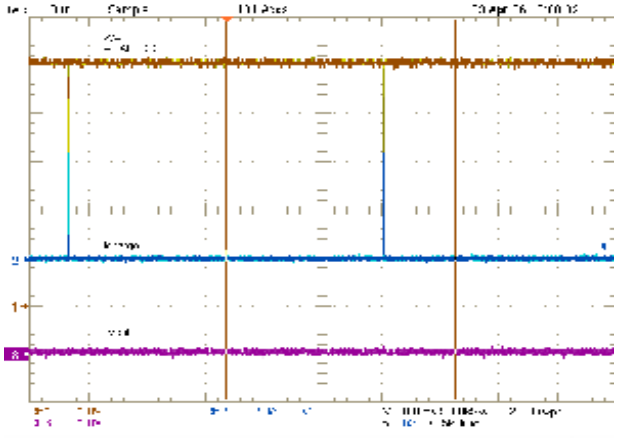


Figure 14. Output Short Circuit

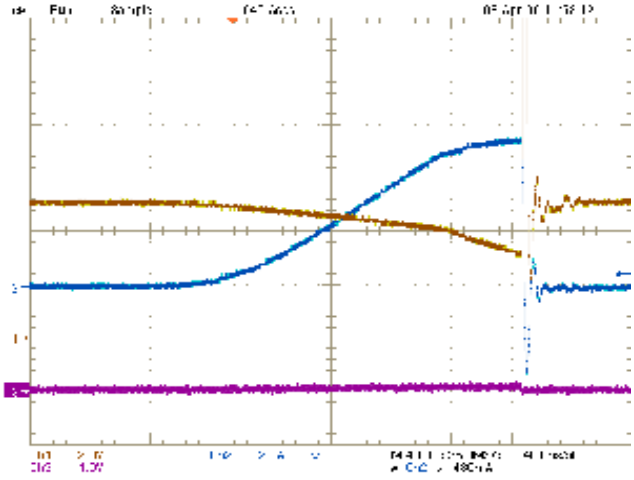


Figure 15. Output Short Circuit (Zoom Fig. 14)

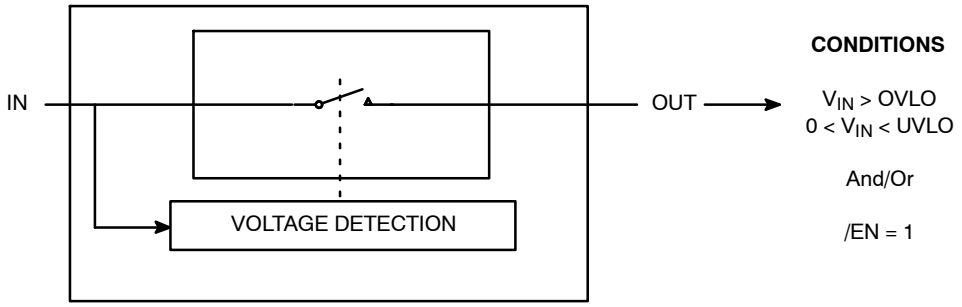


Figure 16. Simplified Diagram

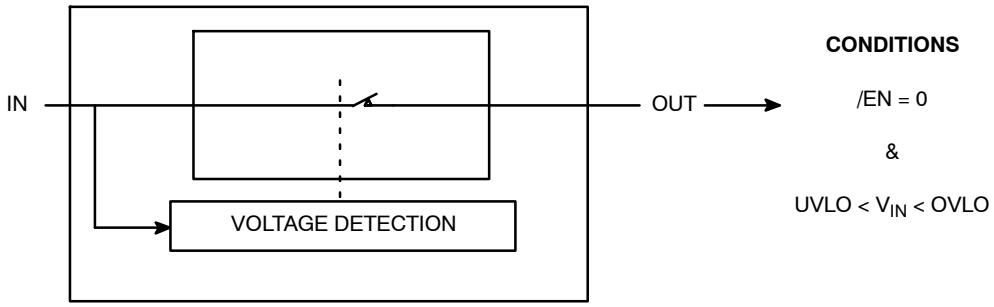


Figure 17. Simplified Diagram

Operation

The NCP348 provides overvoltage protection for positive voltage, up to 28 V. A Low $R_{DS(on)}$ NMOS FET protects the systems (i.e.: charger) connected on the Vout pin, against positive overvoltage. At powerup, with $\overline{EN}$ pin = low, the output is rising up 50 ms after the input overtaking undervoltage UVLO (Figure 3). The NCP348 provides a $\overline{FLAG}$ output, which alerts the system that a fault has occurred. A 50 ms additional delay, regarding available output (Figure 3) is added between output signal rising up and to $\overline{FLAG}$ signal rising up. $\overline{FLAG}$ pin is an open drain output.

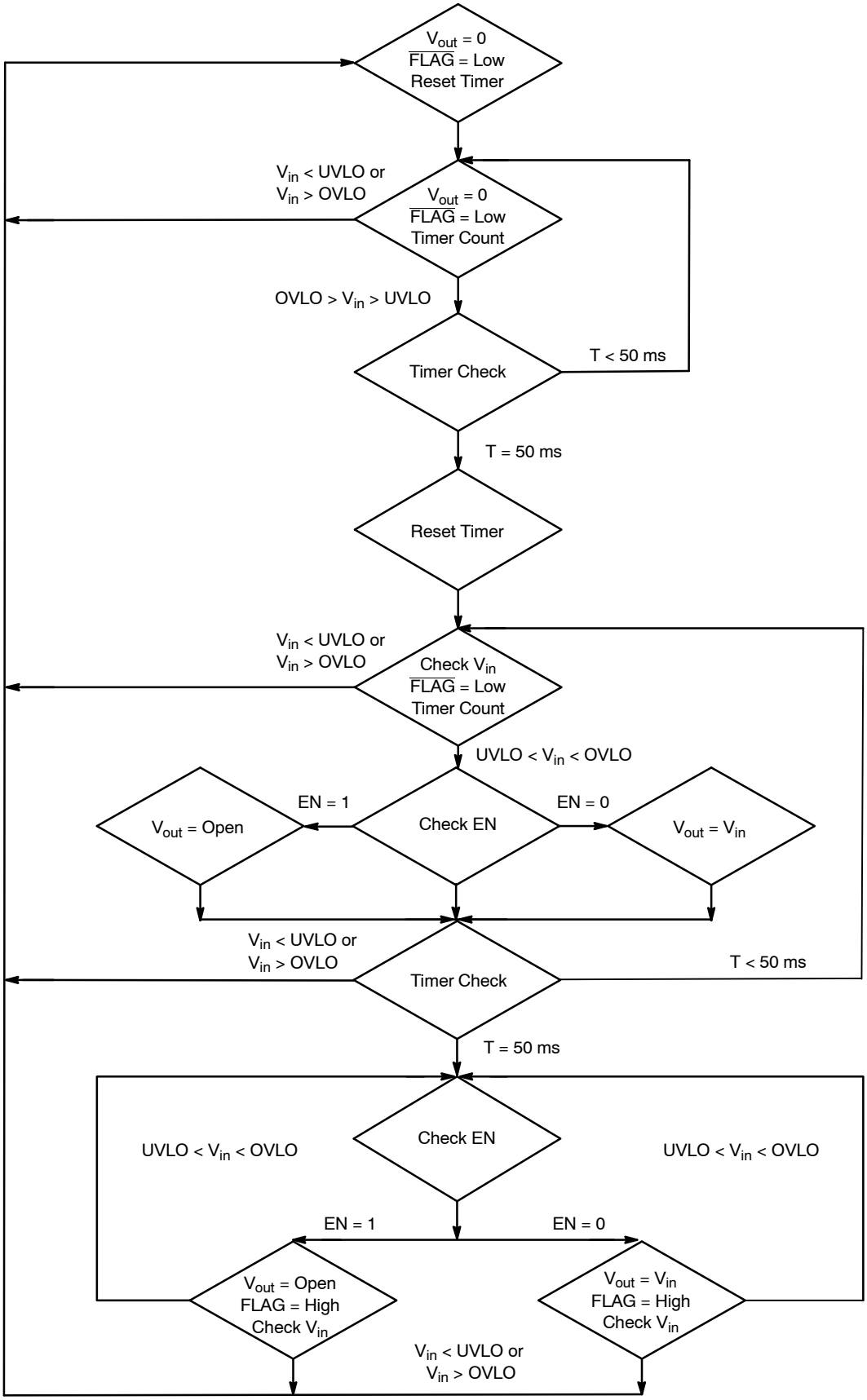


Figure 18. State Machine

Undervoltage Lockout (UVLO)

To ensure proper operation under any conditions, the device has a built−in undervoltage lockout (UVLO) circuit. During V_{in} positive going slope, the output remains disconnected from input until V_{in} voltage is below 3.25 V (NCP348MTT version), plus hysteresis, nominal. The *FLAG* output is tied to low as long as V_{in} does not reach UVLO threshold. This circuit has a 50 mV hysteresis to provide noise immunity to transient condition. Additional UVLO thresholds ranging from UVLO can be manufactured. (See Selection Guide on page 12) Contact your ON Semiconductor representative for availability.

Overvoltage Lockout (OVLO)

To protect connected systems on V_{out} pin from overvoltage, the device has a built−in overvoltage lockout (OVLO) circuit. During overvoltage condition, the output remains disabled as long as the input voltage exceeds 6.4 V typical (NCP348MTT version). Additional OVLO thresholds ranging from OVLO can be manufactured. (See Selection Guide on page 12) Contact your ON Semiconductor representative for availability.

FLAG output is tied to low until V_{in} is higher than OVLO. This circuit has a 100 mV hysteresis to provide noise immunity to transient conditions.

FLAG Output

The NCP348 provides a FLAG output, which alerts external systems that a fault has occurred.

This pin is tied to low as soon the OVLO threshold is exceeded or when the V_{in} level is below the UVLO threshold. When V_{in} level recovers normal condition, FLAG is held high, keeping in mind that an additional 50 ms delay has been added between available output and FLAG = high. The pin is an open drain output, thus a pull up resistor (typically 1 MΩ, minimum 10 kΩ) must be added to V_{bat}. Minimum V_{bat} supply must be 2.5 V. The FLAG level will always reflects V_{in} status, even if the device is turned off ($\overline{EN}$ = 1).

EN Input

To enable normal operation, the *EN* pin shall be forced to low or connected to ground. A high level on the pin, disconnects OUT pin from IN pin. *EN* does not overdrive an OVLO or UVLO fault.

Internal NMOS FET

The NCP348 includes an internal Low $R_{DS(on)}$ NMOS FET to protect the systems, connected on OUT pin, from positive overvoltage. Regarding electrical characteristics, the $R_{DS(on)}$, during normal operation, will create low losses on V_{out} pin.

As example: R_{load} = 8.0 Ω, V_{in} = 5.0 V
Typical $R_{DS(on)}$ = 65 mΩ, I_{out} = 618 mA

V_{out} = 8 x 0.618 = 4.95 V

NMOS losses = $R_{DS(on)}$ x $Iout^2$ = 0.065 x 0.618^2 = 25 mW

ESD Tests

The NCP348 input pin fully supports the IEC61000−4−2. 1.0 μF (minimum) must be connected between V_{in} and GND, close to the device.

That means, in Air condition, V_{in} has a ±15 kV ESD protected input. In Contact condition, V_{in} has ±8.0 kV ESD protected input.

Please refer to Figure 19 to see the IEC 61000−4−2 electrostatic discharge waveform.

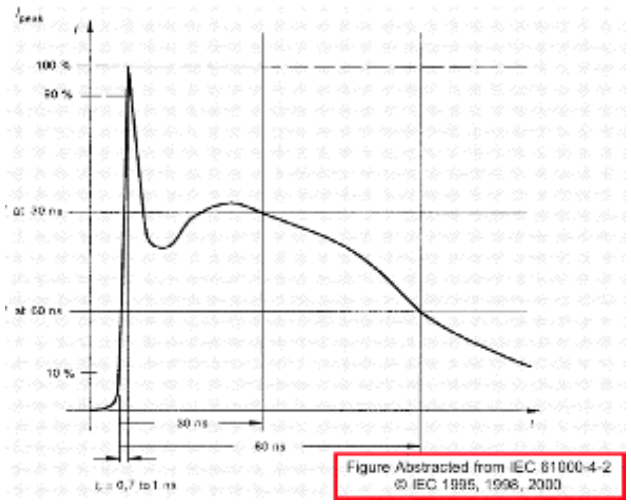


Figure 19. Electrostatic Discharge Waveform

PCB Recommendations

The NCP348 integrates a 2 amperes rated NMOS FET, and the PCB rules must be respected to properly evacuate the heat out of the silicon. The PAD1 is internally isolated from the active silicon and should preferably be connected to ground. The PAD2 of the NCP348 package is connected to the internal NMOS drain and can be used to increase the heat transfer if necessary from an applications standpoint.

Depending upon the power dissipated in the application, one can either use the PCB tracks connected to Pins 4 and 5 to evacuate heat, or make profit of the PAD2 area to add extra copper surface to reduce the junction temperature (See Figure 20). Of course, in any case, this pad shall be not connected to any other potential. Figure 20 shows copper area according to $R_{\theta JA}$ and allows the design of the heat transfer plane connected to PAD2.

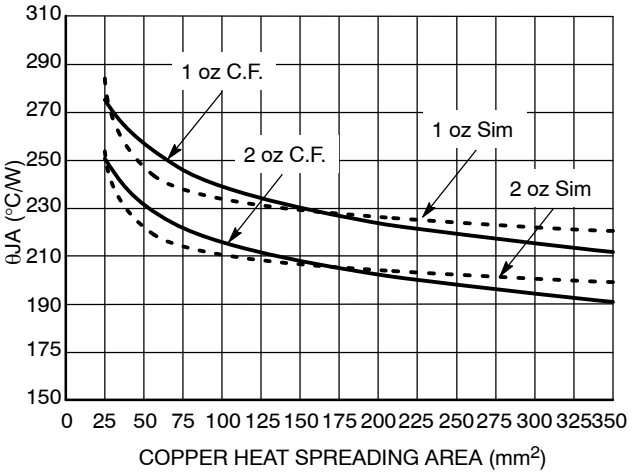


Figure 20.

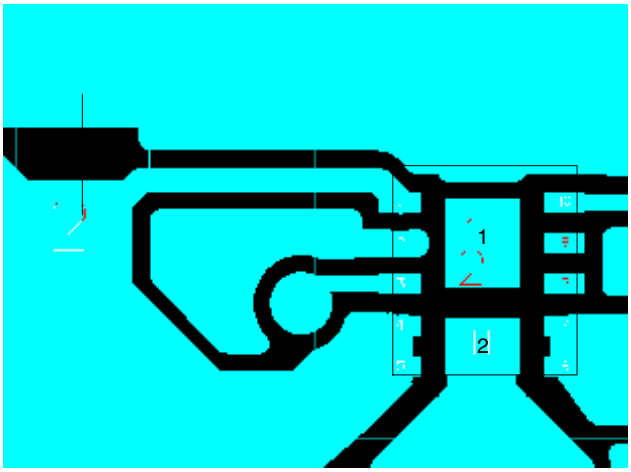


Figure 21. Demo Board Layout

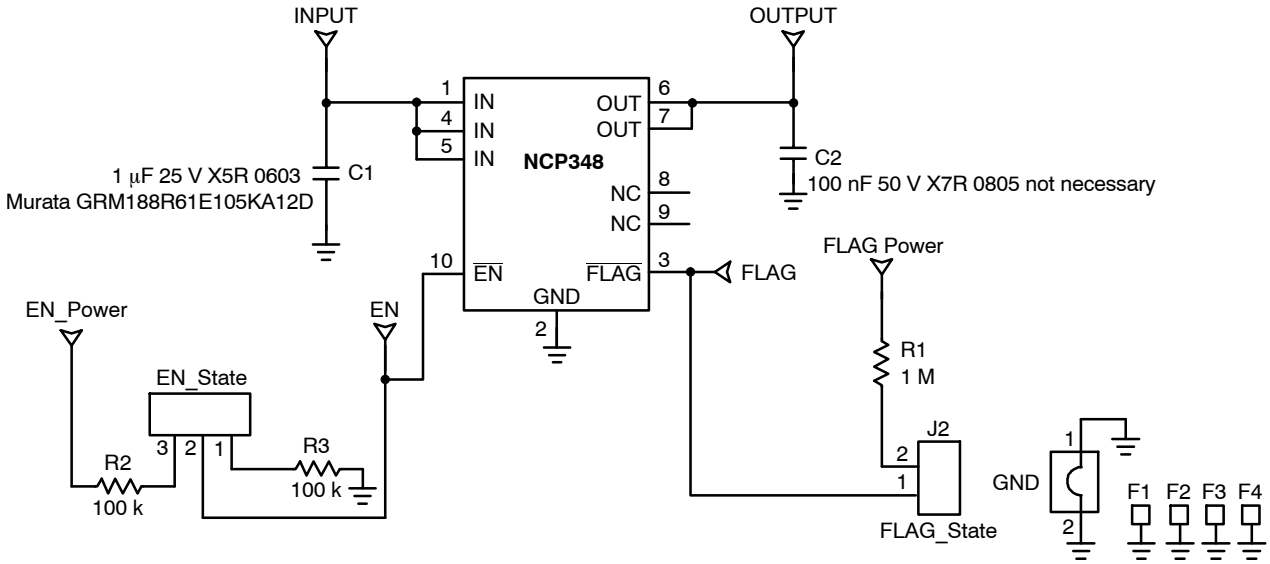


Figure 22. Demo Board Schematic

ORDERING INFORMATION

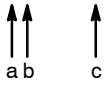
Device	Package	Shipping†
NCP348MTTBG	WDFN−10 (Pb−Free)	3000 / Tape & Reel
NCP348MTTXG	WDFN−10 (Pb−Free)	10000 / Tape & Reel
NCP348AEMTTBG	WDFN−10 (Pb−Free)	3000 / Tape & Reel
NCP348AEMTTXG	WDFN−10 (Pb−Free)	10000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SELECTION GUIDE

The NCP348 can be available in several undervoltage and overvoltage thresholds versions. Part number is designated as follows:

NCP348xxMTTxG



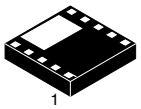
Code	Contents
a	UVLO Typical Threshold a: − = 3.25 V a: A = 3.25 V
b	OVLO Typical Threshold b: − = 6.4 V b: E = 6.02 V
c	Tape & Reel Type c: B = 3000 c: X = 10000

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

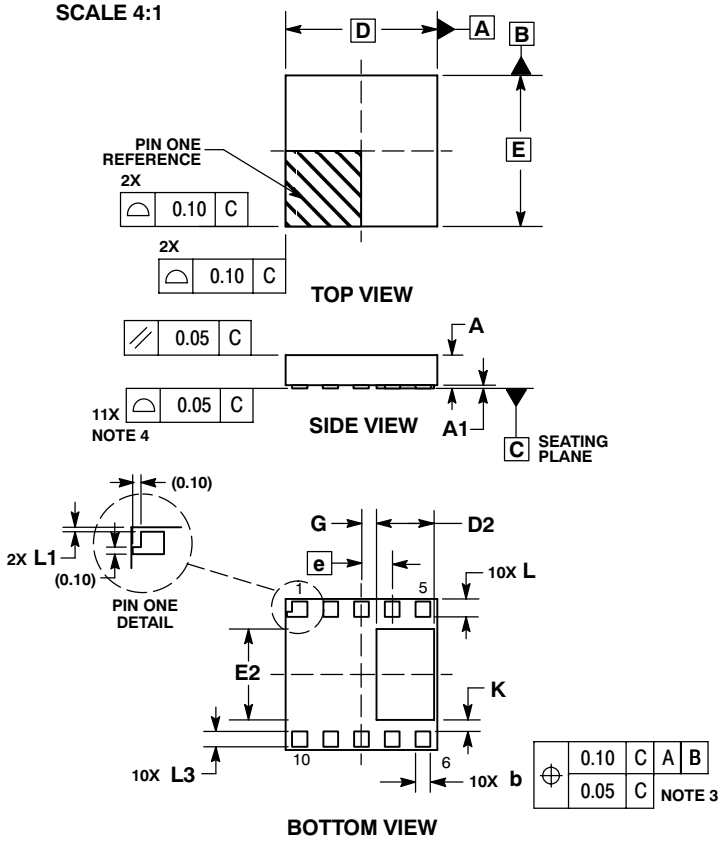
ON Semiconductor®

LLGA10 2.5x2.5, 0.5P
CASE 513AG-01
ISSUE A

DATE 15 MAY 2007



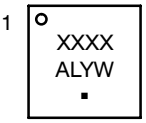
SCALE 4:1



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PADS AS WELL AS THE TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.50	0.60
A1	0.00	0.05
b	0.20	0.30
D	2.50 BSC	
D2	0.90	1.00
E	2.50 BSC	
E2	1.45	1.55
e	0.50 BSC	
G	0.20	0.30
K	0.20	---
L	0.30 REF	
L1	0.05 BSC	
L3	0.20	0.30

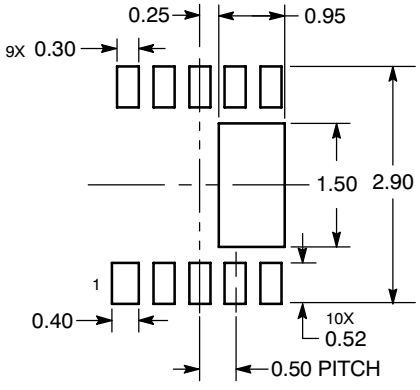
GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
AL = Assembly Location
Y = Year
W = Work Week
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, “G” or microdot “ ▪”, may or may not be present.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON24198D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
STATUS:	ON SEMICONDUCTOR STANDARD		
NEW STANDARD:			
DESCRIPTION:	10 PIN LLGA, 2.5X2.5, 0.5P		PAGE 1 OF 2

ISSUE	REVISION	DATE
O	RELEASED FOR PRODUCTION. REQ. BY W. CLEMENS.	09 MAR 2007
A	ADDED DEVICE MARKING INFORMATION. REQ. BY W. CLEMENS.	15 MAY 2007

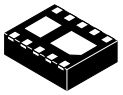
ON Semiconductor and ON are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

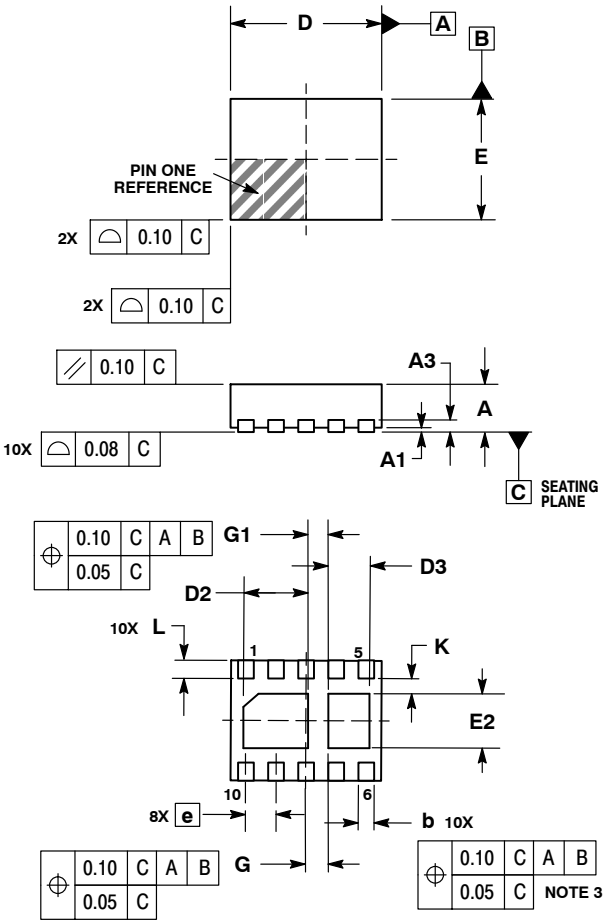
ON Semiconductor®

WDFN10 2.5x2, 0.5P
CASE 516AA−01
ISSUE C

DATE 06 FEB 2007



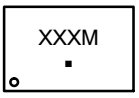
SCALE 4:1



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	---	0.05
A3		0.20 REF	
b	0.20	0.25	0.30
D		2.50 BSC	
D2	0.97	1.08	1.18
D3	0.57	0.68	0.78
e		0.50 BSC	
E		2.00 BSC	
E2	0.80	0.90	1.00
G		0.375 BSC	
G1		0.35 BSC	
K	0.20	---	---
L	0.20	0.30	0.40

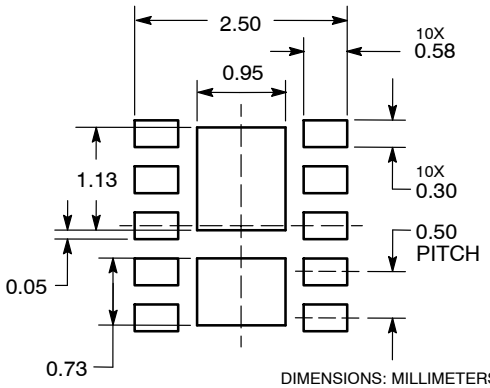
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	**98AON21397D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**WDFN10 2.5X2, 0.5P**	**PAGE 1 OF 1**

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative

◊